

54F/74F157A Quad 2-Input Multiplexer

General Description

The 'F157A is a high-speed quad 2-input multiplexer. Four bits of data from two sources can be selected using the common Select and Enable inputs. The four outputs present the selected data in the true (non-inverted) form. The 'F157A can also be used to generate any four of the 16 different functions to two variables.

Features

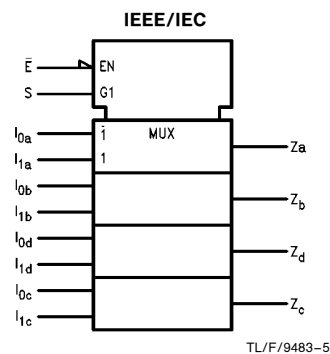
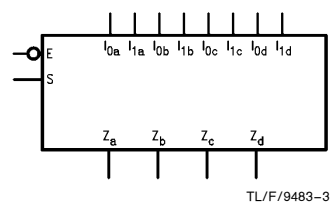
- Guaranteed 4000V minimum ESD protection

Commercial	Military	Package Number	Package Description
74F157APC		N16E	16-Lead (0.300" Wide) Molded Dual-In-Line
	54F157ADM (Note 2)	J16A	16-Lead Ceramic Dual-In-Line
74F157ASC (Note 1)		M16A	16-Lead (0.150" Wide) Molded Small Outline, JEDEC
74F157ASJ (Note 1)		M16D	16-Lead (0.300" Wide) Molded Small Outline, EIAJ
	54F157AFM (Note 2)	W16A	16-Lead Cerpack
	54F157ALM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

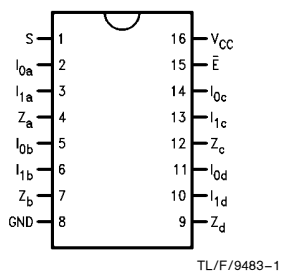
Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMOB, FMOB and LMOB.

Logic Symbols

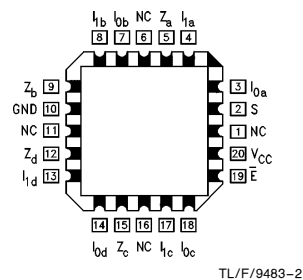


Connection Diagrams

**Pin Assignment
for DIP, SOIC and Flatpak**



**Pin Assignment
for LCC**



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Unit Loading/Fan Out

Pin Names	Description	54F/74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$I_{0a}-I_{0d}$	Source 0 Data Inputs	1.0/1.0	20 μ A/ -0.6 mA
$I_{1a}-I_{1d}$	Source 1 Data Inputs	1.0/1.0	20 μ A/ -0.6 mA
$\bar{E}$	Enable Input (Active LOW)	1.0/1.0	20 μ A/ -0.6 mA
S	Select Input	1.0/1.0	20 μ A/ -0.6 mA
Z_a-Z_d	Outputs	50/33.3	-1 mA/20 mA

Functional Description

The 'F157A is a quad 2-input multiplexer. It selects four bits of data from two sources under the control of a common Select input (S). The Enable input ($\bar{E}$) is active LOW. When $\bar{E}$ is HIGH, all of the outputs (Z) are forced LOW regardless of all other inputs. The 'F157A is the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select input. The logic equations for the outputs are shown below:

$$Z_n = \bar{E} \cdot (I_{1n} S + I_{0n} \bar{S})$$

A common use of the 'F157A is the moving of data from two groups of registers to four common output busses. The particular register from which the data comes is determined by the state of the Select input. A less obvious use is as a function generator. The 'F157A can generate any four of the

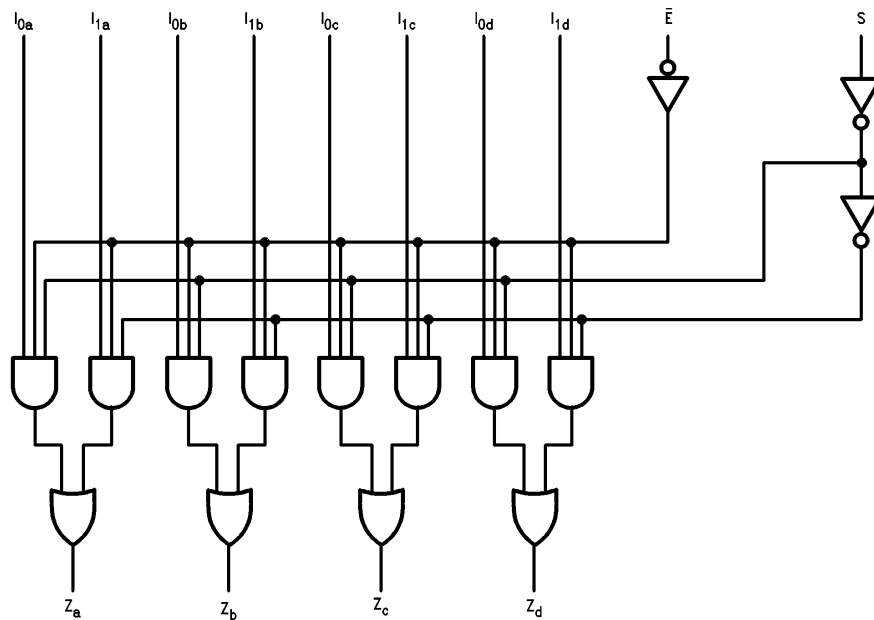
16 different functions of two variables with one variable common. This is useful for implementing highly irregular logic.

Truth Table

Inputs				Output
$\bar{E}$	S	I_0	I_1	Z
H	X	X	X	L
L	H	X	L	L
L	H	X	H	H
L	L	L	X	L
L	L	H	X	H

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Logic Diagram



TL/F/9483-4

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
Plastic	−55°C to +150°C
V _{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V _{CC} = 0V)	
Standard Output	−0.5V to V _{CC}
TRI-STATE® Output	−0.5V to +5.5V

Current Applied to Output in LOW State (Max) twice the rated I_{OL} (mA)

ESD Last Passing Voltage (Min) 4000V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	−55°C to +125°C
Commercial	0°C to +70°C
Supply Voltage	
Military	+4.5V to +5.5V
Commercial	+4.5V to +5.5V

DC Electrical Characteristics

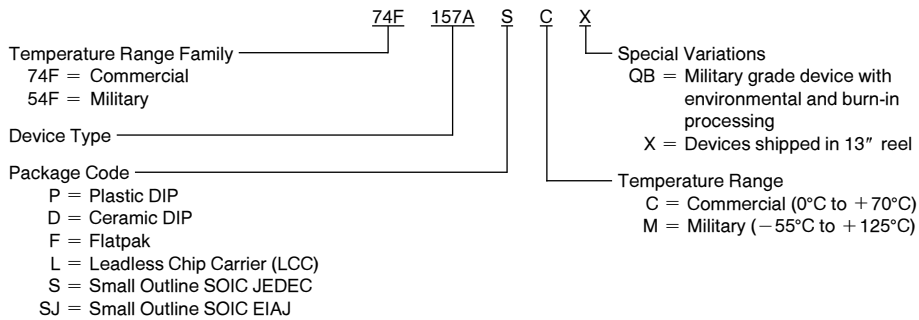
Symbol	Parameter	54F/74F			Units	V _{CC}	Conditions
		Min	Typ	Max			
V _{IH}	Input HIGH Voltage	2.0			V		Recognized as a HIGH Signal
V _{IL}	Input LOW Voltage			0.8	V		Recognized as a LOW Signal
V _{CD}	Input Clamp Diode Voltage			−1.2	V	Min	I _{IN} = −18 mA
V _{OH}	Output HIGH Voltage	54F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC}	2.5 2.5 2.7		V	Min	I _{OH} = −1 mA I _{OH} = −1 mA I _{OH} = −1 mA
V _{OL}	Output LOW Voltage	54F 10% V _{CC} 74F 10% V _{CC}		0.5 0.5	V	Min	I _{OL} = 20 mA I _{OL} = 20 mA
I _{IH}	Input HIGH Current	54F 74F		20.0 5.0	μA	Max	V _{IN} = 2.7V
I _{BVI}	Input HIGH Current Breakdown Test	54F 74F		100 7.0	μA	Max	V _{IN} = 7.0V
I _{CEX}	Output HIGH Leakage Current	54F 74F		250 50	μA	Max	V _{OUT} = V _{CC}
V _{ID}	Input Leakage Test	74F	4.75		V	0.0	I _{ID} = 1.9 μA All Other Pins Grounded
I _{OD}	Output Leakage Circuit Current	74F		3.75	μA	0.0	V _{IOD} = 150 mV All Other Pins Grounded
I _{IL}	Input LOW Current			−0.6	mA	Max	V _{IN} = 0.5V
I _{OS}	Output Short-Circuit Current	−60		−150	mA	Max	V _{OUT} = 0V
I _{CCH}	Power Supply Current		15	23	mA	Max	V _O = HIGH
I _{CCL}	Power Supply Current		15	23	mA	Max	V _O = LOW

AC Electrical Characteristics

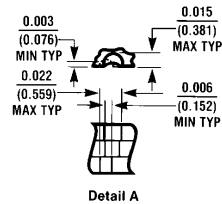
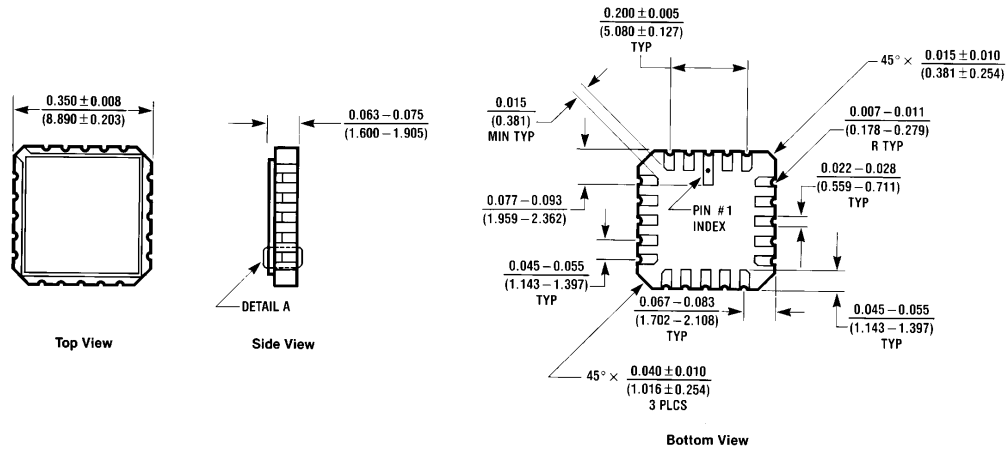
Symbol	Parameter	74F			54F		74F		Units
		$T_A = +25^{\circ}\text{C}$ $V_{CC} = +5.0\text{V}$ $C_L = 50\text{ pF}$			$T_A, V_{CC} = \text{Mil}$ $C_L = 50\text{ pF}$		$T_A, V_{CC} = \text{Com}$ $C_L = 50\text{ pF}$		
		Min	Typ	Max	Min	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay S to Z_n	4.0 3.0	7.0 5.0	10.0 7.0	4.0 3.0	12.0 9.0	4.0 3.0	11.0 8.0	ns
t_{PLH} t_{PHL}	Propagation Delay $\bar{E}$ to Z_n	5.0 2.5	7.0 4.5	9.5 6.5	5.0 2.5	13.0 7.5	5.0 2.5	11.0 7.0	ns
t_{PLH} t_{PHL}	Propagation Delay I_n to Z_n	2.5 2.5	4.5 4.0	6.0 5.5	2.5 1.5	7.5 7.5	2.5 2.0	6.5 7.0	ns

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

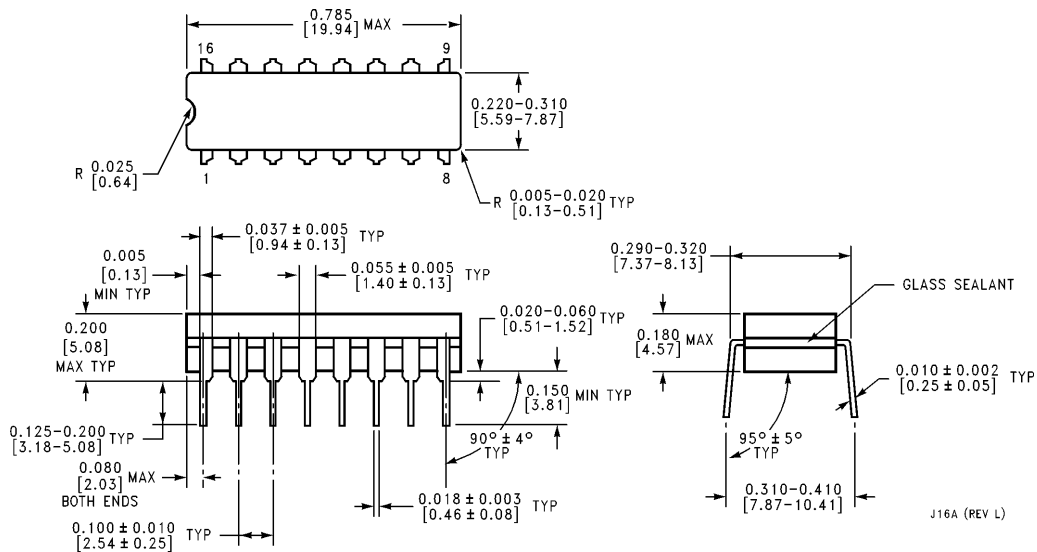


Physical Dimensions inches (millimeters)



**20-Lead Ceramic Leadless Chip Carrier (L)
NS Package Number E20A**

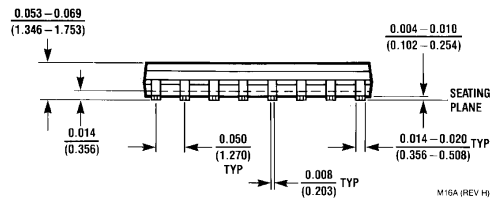
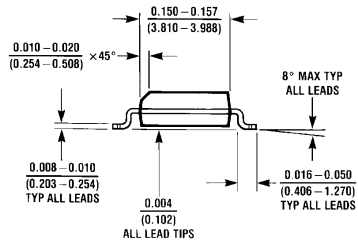
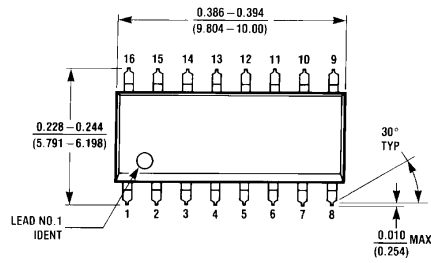
E20A (REV D)



**16-Lead Ceramic Dual In-Line Package (D)
NS Package Number J16A**

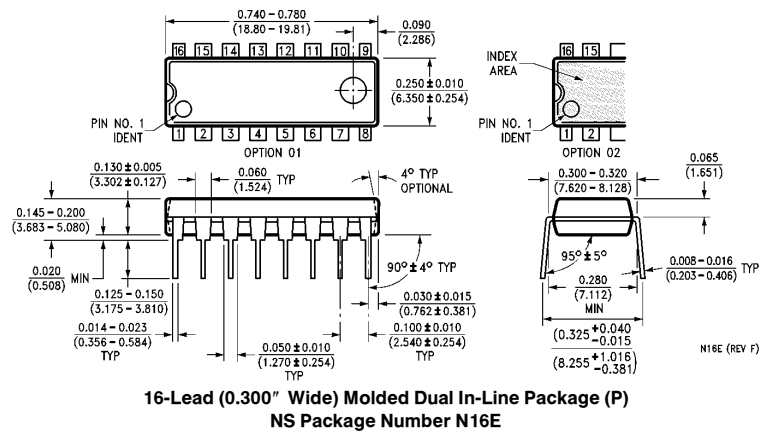
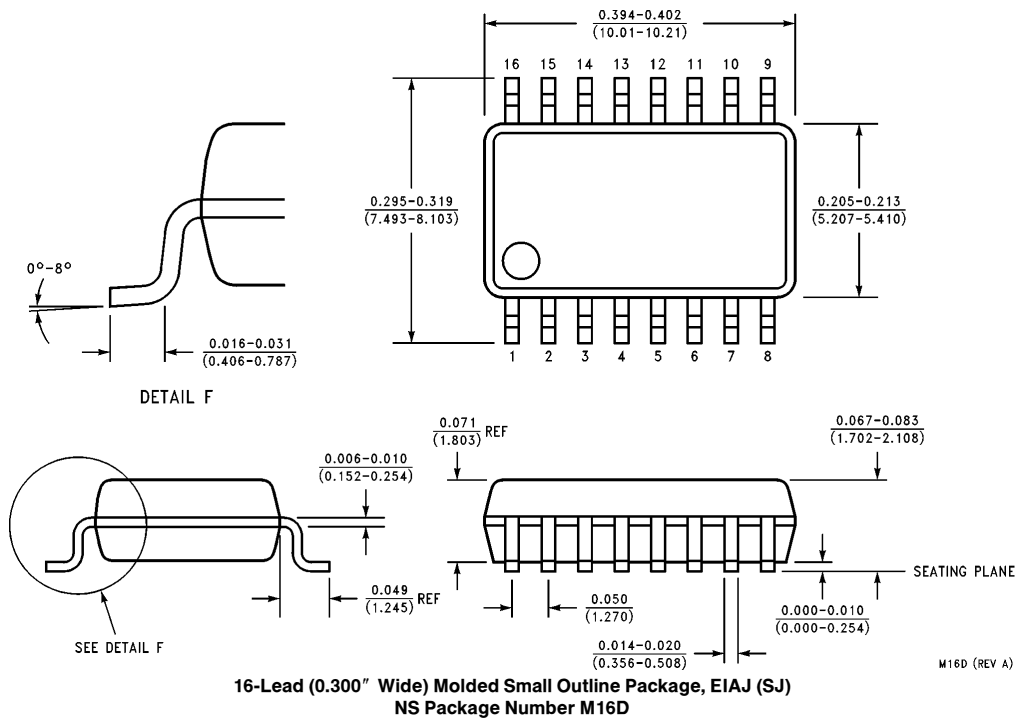
J16A (REV L)

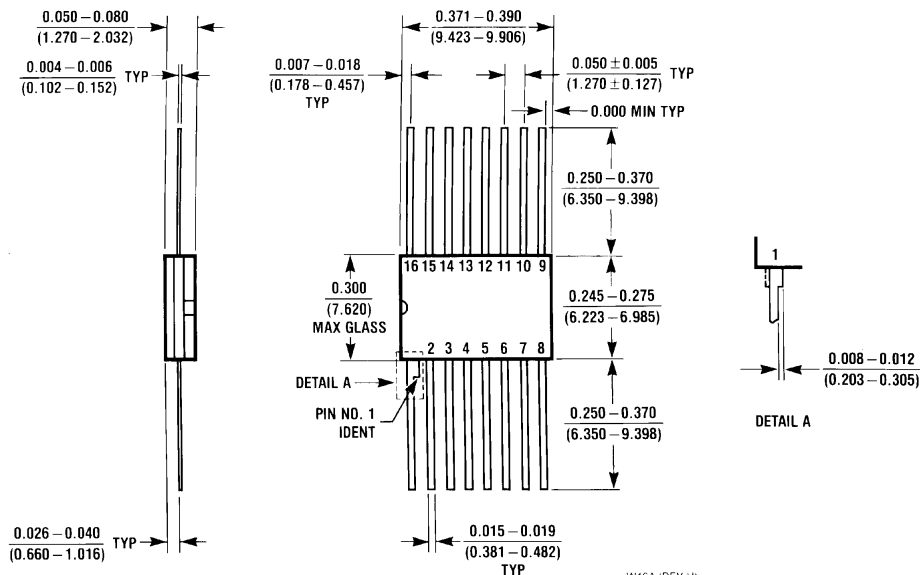
Physical Dimensions inches (millimeters) (Continued)



16-Lead (0.150" Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M16A

Physical Dimensions inches (millimeters) (Continued)



Physical Dimensions inches (millimeters) (Continued)**LIFE SUPPORT POLICY**

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